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#### 1.225V micropower shunt voltage reference

#### **Features**

- 1.225V typical output voltage
- Ultra low operating current: 45µA maximum at 25°C
- High precision @ 25°C
  - +/- 2% (standard version)
  - +/- 1% (A grade)
  - +/- 0.5% (B grade)
- High stability when used with capacitive loads
- Industrial temperature range: -40°C to +85°C
- 120ppm/°C maximum temperature coefficient

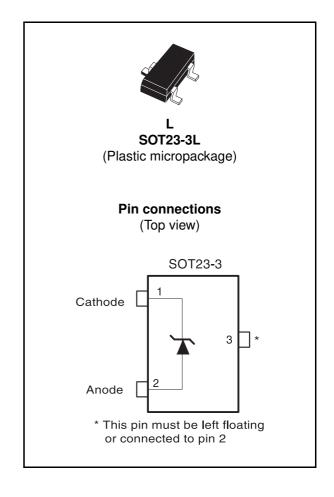
#### **Applications**

- Computers
- Instrumentation
- Battery chargers
- Switch mode power supply
- Battery operated equipment

#### **Description**

The TS821 is a low power shunt voltage reference providing a stable 1.225V output voltage over the industrial temperature range (-40°C to +85°C). Availabe in SOT23-3 surface mount package, it can be designed in applications where space saving is critical.

The low operating current is a key advantage for power restricted designs. In addition, the TS821 is very stable and can be used in a broad range of application conditions.



### 1 Absolute maximum ratings and operating conditions

Table 1. Absolute maximum ratings (AMR)

Symbol	Parameter	Value	Unit		
I <sub>k</sub>	Reverse breakdown current	20	mA		
I <sub>f</sub>	Forward current	10	mA		
P <sub>d</sub>	Power dissipation <sup>(1)</sup> SOT23-3 360				
T <sub>stg</sub>	Storage temperature	-65 to +150	°C		
ESD	Human body model (HBM) <sup>(2)</sup>	2	kV		
LSD	Machine model (MM) <sup>(3)</sup>	200	V		
T <sub>lead</sub>	Lead temperature (soldering, 10 seconds)	260	°C		

<sup>1.</sup>  $P_d$  is calculated with  $T_{amb}$  = 25°C and  $T_j$  = 150°C and  $R_{thja}$  = 340°C/W for the SOT23-3L package.

Table 2. Operating conditions

Symbol	Parameter	Value	Unit
I <sub>min</sub>	Minimum operating current	45	μΑ
I <sub>max</sub>	Maximum operating current	12	mA
T <sub>oper</sub>	Operating free air temperature range	-40 to +85	°C

<sup>2.</sup> Human body model: 100pF discharged through a  $1.5k\Omega$  resistor between two pins of the device, done for all couples of pin combinations with other pins floating.

<sup>3.</sup> Machine model: a 200pF cap is charged to the specified voltage, then discharged directly between two pins of the device with no external series resistor (internal resistor  $< 5\Omega$ ), done for all couples of pin combinations with other pins floating.

### 2 Electrical characteristics

Table 3. TS821 (2% precision)  $T_{amb} = 25^{\circ}C^{(1)}$  (unless otherwise specified)

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit		
	Reverse breakdown voltage	I <sub>k</sub> = 100μA	1.200	1.225	1.250	٧		
V <sub>k</sub>	Reverse breakdown voltage tolerance	$I_k = 100 \mu A$ -40°C < $T_{amb}$ < +85°C	-25 +34		+25 +34	mV		
1	Minimum operating current	T <sub>amb</sub> = 25°C		40	45			
I <sub>k-min</sub>	Average temperature coefficient	-40°C < T <sub>amb</sub> < +85°C			50	<del></del> μΑ		
$\Delta V_{ref}/\Delta T$	Average temperature coefficient	I <sub>k</sub> = 100μA			120	ppm/°C		
$\Delta V_{\mathbf{k}}/\Delta I_{\mathbf{k}}$	Reverse breakdown voltage change	$\begin{aligned} & I_{k\text{-min}} < I_k < 1\text{mA} \\ & -40^{\circ}\text{C} < T_{\text{amb}} < +85^{\circ}\text{C} \end{aligned}$		0.3	0.7 1	. mV		
Δ <b>ν</b> κ/Δικ	with operating current range	1mA < I <sub>k</sub> < 12mA -40°C < T <sub>amb</sub> < +85°C		2.5	8 10	111 <b>V</b>		
R <sub>ka</sub>	Static impedance	$\Delta I_k = 45 \mu A$ to 1mA		0.25	0.5	Ω		
K <sub>vh</sub>	Long term stability	$I_k = 100 \mu A, t = 1000 hrs$		120		ppm		
En	Wide band noise	$I_k = 100 \mu A, 10 Hz < f < 10 kHz$		200		nV/√Hz		

Limits are 100% production tested at 25°C. Behavior at the temperature range limits is guaranteed through correlation and by design.

Table 4. TS821A (1% precision)  $T_{amb} = 25^{\circ}C^{(1)}$  (unless otherwise specified)

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
	Reverse breakdown voltage	$I_k = 100 \mu A$	1.213	1.225	1.237	V
V <sub>k</sub>	Reverse breakdown voltage tolerance	$I_k = 100 \mu A$ -40°C < $T_{amb}$ < +85°C	-12 -22		+12 +22	mV
	Minimum operating current	T <sub>amb</sub> = 25°C		40	45	
l <sub>k-min</sub>	willimum operating current	-40°C < T <sub>amb</sub> < +85°C			50	μΑ
$\Delta V_{ref}/\Delta T$	Average temperature coefficient	$I_k = 100 \mu A$			120	ppm/°C
AV /AI	Reverse breakdown voltage change	$I_{k-min} < I_k < 1mA$ -40°C < $T_{amb}$ < +85°C		0.3	0.7 1	mV
$\Delta V_k/\Delta I_k$	with operating current range	1mA < I <sub>k</sub> < 12mA -40°C < T <sub>amb</sub> < +85°C		2.5	5 7	IIIV
R <sub>ka</sub>	Static impedance	$\Delta I_k = 45\mu A$ to 1mA		0.25	0.5	Ω
K <sub>vh</sub>	Long term stability	$I_k = 100 \mu A, t = 1000 hrs$		120		ppm
En	Wide band noise	$I_{k} = 100 \mu A \ 10 Hz < f < 10 kHz$		200		nV/√Hz

Limits are 100% production tested at 25°C. Behavior at the temperature range limits is guaranteed through correlation and by design.

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Electrical characteristics TS821

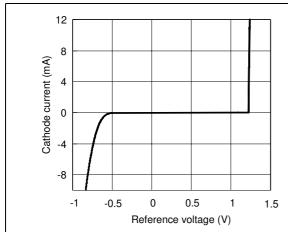
Table 5. TS821B (0.5% precision)  $T_{amb} = 25^{\circ}C^{(1)}$  (unless otherwise specified)

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
	Reverse breakdown voltage	I <sub>k</sub> = 100μA	1.219	1.225	1.231	٧
V <sub>k</sub>	Reverse breakdown voltage tolerance	$I_k = 100 \mu A$ -40°C < $T_{amb}$ < +85°C	-6 -16		+6 +16	mV
	Minimum operating current	T <sub>amb</sub> = 25°C		40	45	
¹k-min	I <sub>k-min</sub> Minimum operating current	-40°C < T <sub>amb</sub> < +85°C			50	μΑ
$\Delta V_{ref}/\Delta T$	Average temperature coefficient	I <sub>k</sub> = 100μA			120	ppm/°C
$\Delta V_{\mathbf{k}}/\Delta I_{\mathbf{k}}$	Reverse breakdown voltage change	$\begin{aligned} & I_{\text{k-min}} < I_{\text{k}} < 1\text{mA} \\ & -40^{\circ}\text{C} < T_{\text{amb}} < +85^{\circ}\text{C} \end{aligned}$		0.3	0.7 1	mV
Δ <b>ν</b> <sub>k</sub> /Δι <sub>k</sub>	with operating current range	1mA < I <sub>k</sub> < 12mA -40°C < T <sub>amb</sub> < +85°C		2.5	5 7	1110
R <sub>ka</sub>	Static impedance	$\Delta I_{k} = 45\mu A$ to 1mA		0.25	0.5	W
K <sub>vh</sub>	Long term stability	$I_k = 100 \mu A, t = 1000 hrs$		120		ppm
En	Wide band noise	I <sub>k</sub> = 100μA 10Hz < f < 10kHz		200		nV/√Hz

Limits are 100% production tested at 25°C. Behavior at the temperature range limits is guaranteed through correlation and by design.

TS821 Electrical characteristics

Figure 1. Reference voltage versus cathode Figure 2. Reference voltage versus cathode current



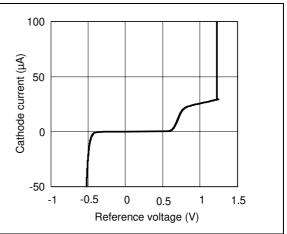
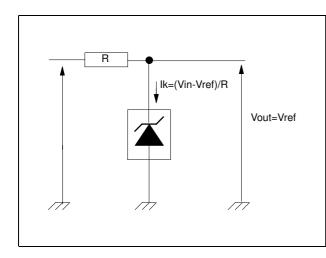


Figure 3. Test circuit

Figure 4. Reference voltage versus temperature



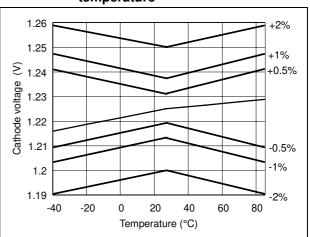
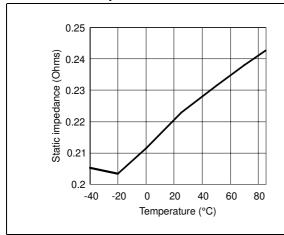
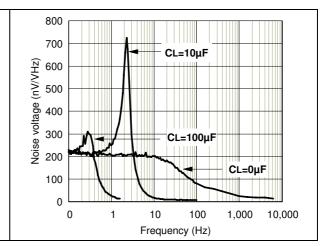


Figure 5. Static impedance versus temperature

Figure 6. Noise voltage versus frequency





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Figure 7. Pulse response for  $I_k=100\mu$ A

Figure 8. Test circuit for pulse response at  $I_k=100\mu A$ 

k=100μA

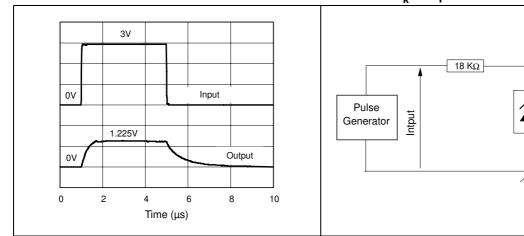
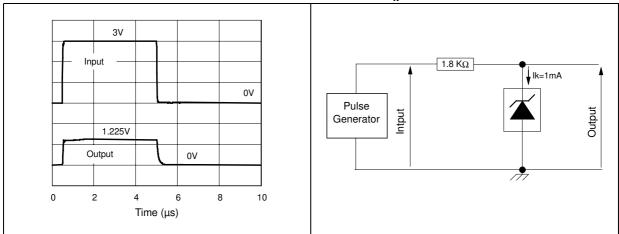


Figure 9. Pulse response for I<sub>k</sub>=1mA

Figure 10. Test circuit for pulse response at  $I_k$ =1mA



### 3 Package information

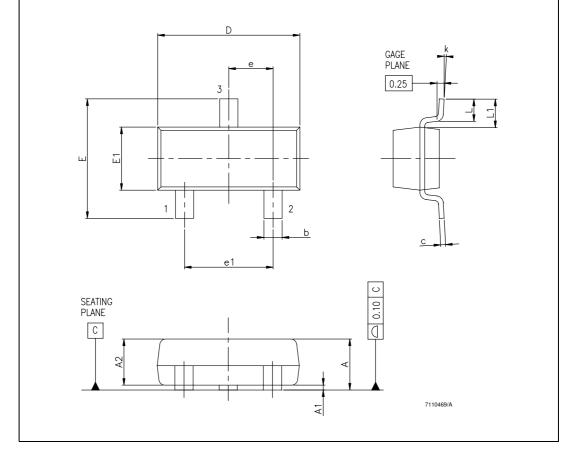
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TS821 Package information

Figure 11. SOT23-3 package mechanical data

			Dimer	nsions				
Ref.		Millimeters			Mils			
	Min.	Тур.	Max.	Min.	Тур.	Max.		
А	0.890		1.120	35.05		44.12		
A1	0.010		0.100	0.39		3.94		
A2	0.880	0.950	1.020	34.65	37.41	40.17		
b	0.300		0.500	11.81		19.69		
С	0.080		0.200	3.15		7.88		
D	2.800	2.900	3.040	110.26	114.17	119.72		
Е	2.100		2.64	82.70		103.96		
E1	1.200	1.300	1.400	47.26	51.19	55.13		
е		0.950			37.41			
e1		1.900			74.82			
L	0.400		0.600	15.75		23.63		
L1		0.540			21.27			
k	0°		8°	0°		8°		



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Ordering information TS821

# 4 Ordering information

Table 6. Order codes

Part number	Precision	Temperature range	Package	Packing	Marking
TS821ILT	2%	1010			L213
TS821AILT	1%	-40°C to +85°C	SOT23-3	Tape & reel	L212
TS821BILT	0.5%				L211

# 5 Revision history

Table 7. Document revision history

Date	Revision	Changes
10-Nov-2005	1	Initial release.
24-Jul-2007	2	Removed information related to TO-92. Format update.

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